



OCTAL BUFFER/LINE DRIVER WITH 3 STATE OUTPUTS

Description

The 74LVC240A provides two 4-bit buffers/drivers with separate output-enable $\overline{(OE)}$ inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

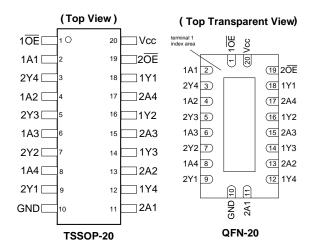
The device is designed for operation with a power supply range of 1.65 V to 3.6 V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using l_{OFF} . The l_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Features

- Supply Voltage Range from 1.65V to 3.6V
- Sinks or Sources 24 ma at V_{CC} = 3V
- CMOS Low Power Consumption
- I_{OFF} Supports Partial -Power Down Operation
- Inputs or Outputs Accept up to 5.5V
- Inputs Can Be Driven by 3.3V or 5V Allowing for Mixed Voltage Applications
- Schmitt Trigger Action at All Inputs
- Typical V_{OLP} (Quiet Output Ground Bounce) Less than 0.8V with $V_{CC} = 3.3V$ and $T_A = +25^{\circ}C$
- Typical V_{OHV} (Quiet Output dynamic VOH) Greater than 2.0V with V_{CC} = 3.3V and T_A = +25°C
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 250mA per JESD 78, Class I
- · All devices are:
 - Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

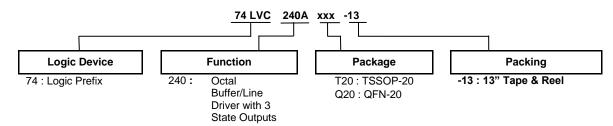
- General Purpose Logic
- Bus Driving
- Power Down Signal Isolation
- Wide Array of Products Such as:
 - PCs, Notebooks, Netbooks, Ultrabooks
 - Networking Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Ordering Information



Part Number	Package	Package	Package Size	13" Tape	and Reel
Fait Number	Code	(Note 4 & 5)	Fackage Size	Quantity	Part Number Suffix
74LVC240AT20-13	T20	TSSOP-20	6.4mm X 6.5mm X 1.2mm 0.65 mm lead pitch	2500/Tape & Reel	-13
74LVC240AQ20-13	Q20	V-QFN4525-20	2.5mm X 4.5mm X 0.95mm 0.50 mm lead pitch	2500/Tape & Reel	-13

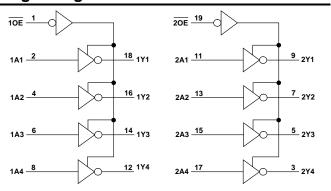
Notes:

- 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 5. V-QFN4525-20 is a JEDEC recognized naming convention that specifies the package thickness category as V and the number 4525 describes the package as 4.5mm X 2.5mm.

Pin Descriptions

Pin Number	Pin Name	Description
1	1OE	Output Enable 1
2	1A1	Data Input
3	2Y4	Data Output
4	1A2	Data Input
5	2Y3	Data Output
6	1A3	Data Input
7	2Y2	Data Output
8	1A4	Data Input
9	2Y1	Data Output
10	GND	Ground
11	2A1	Data Input
12	1Y4	Data Output
13	2A2	Data Input
14	1Y3	Data Output
15	2A3	Data Input
16	1Y2	Data Output
17	2A4	Data Input
18	1Y1	Data Output
19	20E	Output Enable 2
20	Vcc	Supply Voltage

Logic Diagram



Function Table

(Each 4-Bit Buffer)					
INPU	OUTPUT				
ŌĒ	Α	Y			
L	Н	L			
L	L	Н			
Н	Х	Z			



Absolute Maximum Ratings (Notes 6 & 7)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range note 3	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < 0V	-20	mA
lok	Output Clamp Current Vo< 0V	-50	mA
lo	Continuous output current - 0.5V < V _O Vcc + 0.5V	±50	mA
Icc	Continuous current through Vcc	100	mA
I _{GND}	Continuous current through GND	-100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes:

- 6. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
- 7. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Recommended Operating Conditions (Note 8)

Symbol	Parameter	Conditions	Min	Max	Unit	
V	Supply Voltage	Operating	1.65	3.6	V	
Vcc	Supply Voltage	Data Retention Only	1.5	_	V	
Vı	Input Voltage	_	0	5.5	V	
Vo	Output Voltage	_	0	V _{CC}	V	
		V _{CC} = 1.65V	_	-4		
	Lifety Level Output Output	V _{CC} = 2.3V	_	-8	4	
Іон	High-Level Output Current	V _{CC} = 2.7V	_	-12	mA	
		V _{CC} = 3.0V	_	-24		
		V _{CC} = 1.65V	_	4		
	Law Law Louis Outside Outside	V _{CC} = 2.3V	_	8	4	
l _{OL}	Low-Level Output Current	V _{CC} = 2.7V	_	12	mA	
		V _{CC} = 3.0V	_	24		
Δt/ΔV	Input Transition Rise or Fall Rate		_	10	ns/V	
T _A	Operating Free-Air Temperature		-40	+125	°C	

Note:

8. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics

Symbol	Parameter	Test Conditions	V	T _A = -40°0	C to +85°C	T _A = -40°C	to +125°C	Unit
Oyinboi i arametei		rest Conditions	V _{CC}	Min	Max	Min	Max	Onit
	LEab Lavelland		1.65V to 1.95V	V _{CC} X 0.65	_	V _{CC} X 0.65	_	
V_{IH}	High-Level Input Voltage		2.3V to 2.7V	1.7	_	1.7	_	V
	Voltage		3.0V to 3.6V	2	_	2	_	
	Lave Lavalianes		1.65V to 1.95V	_	V _{CC} X 0.35	_	V _{CC} X 0.35	
V_{IL}	Low-Level input voltage		2.3V to 2.7V	_	0.7	_	0.7	V
	remage		3.0V to 3.6V	_	0.8	_	0.8	
		$I_{OH} = -50 \mu A$	1.65V to 3.6V	V _{CC} -0.2	_	V _{CC} -0.3	_	
		$I_{OH} = -4 \text{ mA}$	1.65V	1.2	_	1.05	_	
V_{OH}	High-Level	I _{OH} = -8 mA	2.3V	1.7	_	1.65	_	
VOH	Output Voltage	Ι 40 Λ	2.7V	2.2	_	2.05	_	V
		$I_{OH} = -12 \text{ mA}$	3.0V	2.4	_	2.48	_	V
		I _{OH} = -24 mA	3.0V	2.3	_	2.0	_	
		I _{OL} = 100 μA	1.65V to 3.6V	_	0.2	_	0.3	
		I _{OL} = 4 mA	1.65V	_	0.45	_	0.65	
V_{OL}	Low-Level Output Voltage	I _{OL} = 8 mA	2.3V	_	0.60	_	0.80	V
	Voltage	I _{OL} = 12 mA	2.7V	_	0.40	_	0.60	
		I _{OL} = 24 mA	3.0V	_	0.55	_	0.80	
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 0$ or 5.5V	0V	_	±10	_	20	μΑ
II	Input Current Control Pins	V _I =GND or 5.5V	0 to 3.6V	_	±5	_	± 20	μΑ
l _{OZ}	Z-state Current Including Input Current I/O Pins	V _I =GND or 5.5V V _O = 0 to 5.5V	3.6V	_	±5	_	± 20	uA
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V	_	10	_	40	μΑ
Δl _{CC}	Additional Supply Current	One input at Vcc-0.6V Io= 0A	2.7V to 3.6V	_	500	_	5000	μΑ
Ci	Input Capacitance	Control Pins $V_I = GND$ or I/O Pins V_C	0V to 3.6V		/pical /pical	4.0 ty 5.5 ty	•	pF

Switching Characteristics

Symbol	Parameter	Test	V	-	T _A = +25°(3	-40°C t	o +85°C	-40°C to	+125°C	Unit
Symbol	Farameter	Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Oilit
			1.8V± 0.15V	1.0	6.0	12.2	1.0	13.1	1.0	16.9	
_	Propagation	Figure 1	2.5V± 0.2V	1.0	3.9	7.8	1.0	8.4	1.0	8.9	20
t _{PD}	Delay A _N to Y _N		2.7V	1.0	4.2	8.1	1.0	8.9	1.0	9.0	ns
			3.3V± 0.3V	1.5	3.8	7.6	1.5	8.1	1.5	8.3	
			1.8V± 0.15V	1.0	7.0	14.8	1.0	15.3	1.0	22.5	
4	Enable Time	Figure 1	2.5V± 0.2V	1.0	4.5	10.0	1.0	10.5	1.0	12.4	20
t _{EN}	OE to Y _N		2.7V	1.0	5.4	8.5	1.0	9.5	1.0	11.0	ns
			$3.3 \pm 0.3 \text{V}$	1.5	4.4	7.0	1.5	8.5	1.5	9.0	
			1.8V± 0.15V	1.0	7.8	16.5	1.0	17.0	1.0	18.2	
	Disable Time	Figure 1	2.5V± 0.2V	1.0	4.0	9.0	1.0	9.5	1.0	10.7	20
t _{DIS}	OE to Y _N		2.7V	1.0	4.3	7.5	1.0	8.5	1.0	10.0	ns
			3.3V± 0.3V	1.7	4.0	6.0	1.7	7.5	1.7	9.0	
t _{sk(0)}	Output Skew Time		3.3V± 0.3V	_	_	1.0	_	_	_	1.5	ns



Operating Characteristics

 $T_A = +25$ °C

Symbol	Parameter	Test Conditions	V _{CC}	Тур	Unit
	Dawar Diagination	E 40 MHz	1.8V ± 0.15V	9.9	
C_{pd}	C _{pd} Power Dissipation Capacitance per Gate	F= 10 MHz Outputs Enabled	$2.5V \pm 0.2V$	10.2	pF
			$3.3V \pm 0.3V$	10.6	

Package Characteristics

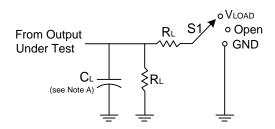
Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
θ_{JA}	Thermal Resistance Junction-to-Ambient	TSSOP-20	(Note 9)	_	74	_	°C/W
θις	Thermal Resistance Junction-to-Case	TSSOP-20	(Note 9)	_	15	_	°C/W
θ _{JA}	Thermal Resistance Junction-to-Ambient	V-QFN4525-20	(Note 9)	_	67	_	°C/W
θ _{JC}	Thermal Resistance Junction-to-Case	V-QFN4525-20	(Note 9)	_	20	_	°C/W

Note:

^{9.} Test conditions for TSSOP-20 and V-QFN4525-20: Devices mounted on 4 layer FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout per JESD 51-7.

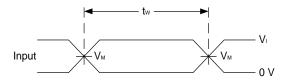


Parameter Measurement Information

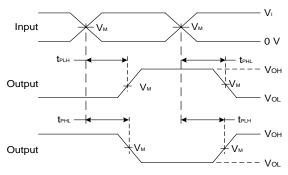


TEST	S 1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V_{LOAD}
t _{PHZ} /t _{PZH}	GND

V	In	puts	, , , , , , , , , , , , , , , , , , ,			В	VA.	
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	C _L	R_L	$\mathbf{V}\Delta$	
1.8V±0.15V	Vcc	≤2ns	V _{CC} /2	2 x V _{CC}	30pF	1ΚΩ	0.15V	
2.5V±0.2V	Vcc	≤2ns	V _{CC} /2	2 x V _{CC}	30pF	500Ω	0.15V	
2.7V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V	
3.3V±0.3V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V	



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Output Control 0 V Output $V_{\text{LOAD}/2}$ Waveform 1 S1 at VLOAD Vol + V (see Note B) Output Vон Waveform 2 Voh - Va S1 at GND (see Note B)

Voltage Waveform Enable and Disable Times Low and High Level Enabling

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLZ} and t_{PHZ} are the same as $t_{dis.}$

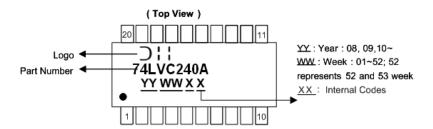
 - E. t_{PZL} and t_{PZH} are the same as t_{EN0} F. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

Figure 1 Load Circuit and Voltage Waveforms



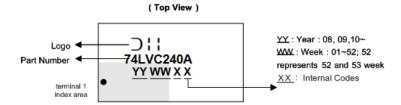
Marking Information

(1) TSSOP20



Part Number	Package
74LVC240AT20	TSSOP-20

(2) QFN-20 (V-QFN4525-20)



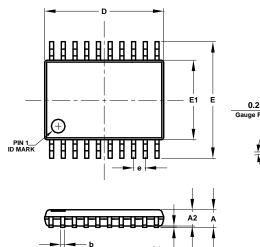
Part Number	Package
74LVC240AQ20	V-QFN4525-20

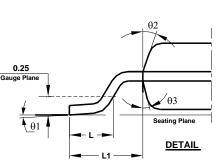


Package Outline Dimensions (All Dimensions in mm)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) TSSOP-20

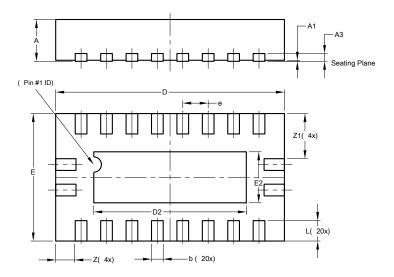




DIM	WIIN	wax	тур
Α	-	1.20	-
A1	0.05	0.15	-
A2	0.80	1.05	-
b	0.19	0.30	-
С	0.09	0.20	-
D	6.40	6.60	6.50
Е	6.20	6.60	6.40
E1	4.30	4.50	4.40
е	0.65 BSC		
L	0.45	0.75	0.60
L1	1.0 REF		
θ1	0°	8°	-
θ2	10°	14°	12°
θ3	10°	14°	12°
All Dimensions in mm			

TSSOP-20

(2) QFN-20 (V-QFN4525-20)



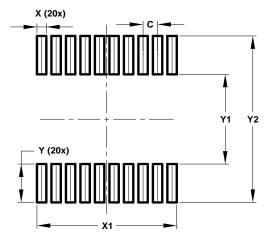
V OFNIERE OF					
	V-QFN4525-20				
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
А3	-	-	0.15		
b	0.18	0.30	0.23		
D	4.45	4.55	4.50		
D2	2.85	3.15	3.00		
Е	2.45	2.55	2.50		
E2	0.85	1.15	1.00		
е	0.50BSC				
L	0.30	0.50	0.40		
Z	-	-	0.385		
Z 1	-	-	0.885		
All Dimensions in mm					



Suggested Pad Layout

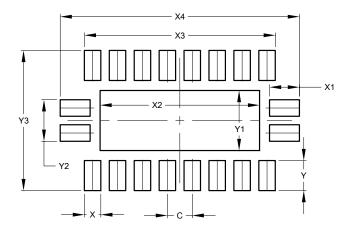
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) TSSOP-20



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	6.270
Υ	1.789
Y1	4.160
Y2	7.720

(2) QFN-20 (V-QFN4525-20)



Dimensions	Value (in mm)
С	0.500
Х	0.330
X1	0.600
X2	3.200
Х3	3.830
X4	4.800
Υ	0.600
Y1	1.200
Y2	0.830
V3	2 800



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